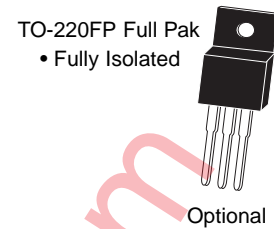
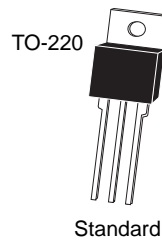


Power Transistors

TO-220 Case



TYPE NO.		I _C	P _D	BV _{CBO}	BV _{CEO}	h _{FE}		@ I _C	V _{CE(SAT)}	@ I _C	f _T
NPN	PNP	(A) MAX	(W)	(V) MIN	(V) MIN	MIN	MAX	(A)	(V) MAX	(A)	(MHz) MIN
2N5294		4.0	36	80	70	30	120	0.5	1.0	0.5	0.8
2N5296		4.0	36	60	40	30	120	1.0	1.0	1.0	0.8
2N5298		4.0	36	80	60	20	80	1.5	1.0	1.5	0.8
2N5490		7.0	50	60	40	20	100	2.0	1.0	2.0	0.8
2N5492		7.0	50	75	55	20	100	2.5	1.0	2.5	0.8
2N5494		7.0	50	60	40	20	100	3.0	1.0	3.0	0.8
2N5496		7.0	50	90	70	20	100	3.5	1.0	3.5	0.8
2N6043	2N6040	10	75	60	60	1,000	20,000	4.0	2.0	4.0	4.0
2N6044	2N6041	10	75	80	80	1,000	20,000	4.0	2.0	4.0	4.0
2N6045	2N6042	10	75	100	100	1,000	20,000	3.0	2.0	3.0	4.0
2N6099		10	75	70	60	20	80	4.0	2.5	10	5.0
2N6101		10	75	80	70	20	80	5.0	2.5	10	5.0
2N6103		16	75	45	40	15	80	8.0	2.5	16	5.0
2N6121	2N6124	4.0	40	45	45	25	100	1.5	0.6	1.5	2.5
2N6122	2N6125	4.0	40	60	60	25	100	1.5	0.6	1.5	2.5
2N6123	2N6126	4.0	40	80	80	20	80	1.5	0.6	1.5	2.5
2N6129	2N6132	7.0	50	40	40	20	100	2.5	1.4	7.0	2.5
2N6130	2N6133	7.0	50	60	60	20	100	2.5	1.4	7.0	2.5
2N6131	2N6134	7.0	50	80	80	20	100	2.5	1.8	7.0	2.5
2N6288	2N6111	7.0	40	40	30	30	150	2.0	3.5	7.0	4.0
2N6290	2N6109	7.0	40	60	50	30	150	2.5	3.5	7.0	4.0
2N6292	2N6107	7.0	40	80	70	30	150	3.0	3.5	7.0	4.0
2N6386	2N6666	8.0	65	40	40	1,000	20,000	3.0	2.0	3.0	20
2N6387	2N6667	10	65	60	60	1,000	20,000	5.0	2.0	5.0	20
2N6388	2N6668	10	65	80	80	1,000	20,000	5.0	2.0	5.0	20
2N6473	2N6475	4.0	40	110	100	15	150	1.5	1.2	1.5	4.0
2N6474	2N6476	4.0	40	130	120	15	150	1.5	1.2	1.5	4.0
2N6486	2N6489	15	75	50	40	20	150	5.0	1.3	5.0	5.0
2N6487	2N6490	15	75	70	60	20	150	5.0	1.3	5.0	5.0
2N6488	2N6491	15	75	90	80	20	150	5.0	1.3	5.0	5.0

Shaded areas indicate Darlington.

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